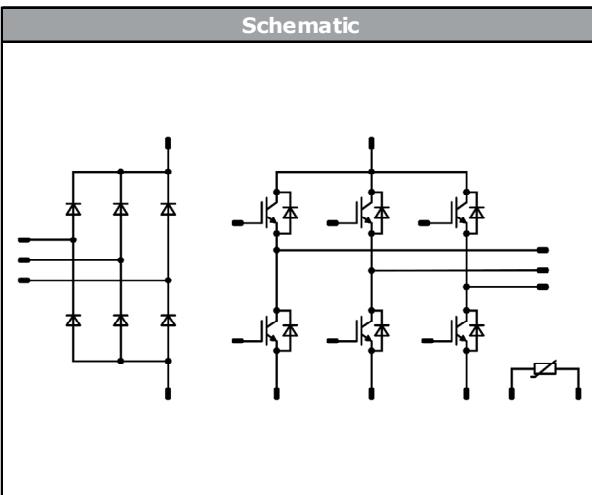




10-FZ12PNA015M7-P840C28

datasheet

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| flow PIM 0 | | 1200 V / 15 A |
|----------------------------|--|---|
| Features | |  |
| | <ul style="list-style-type: none">• IGBT M7 with low V_{CEsat} and improved EMC behavior• Open emitter configuration• Compact and low inductive design• Built-in NTC | |
| Target applications | | Schematic |
| | <ul style="list-style-type: none">• Industrial Drives |  |
| Types | | |
| | <ul style="list-style-type: none">• 10-FZ12PNA015M7-P840C28 | |

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|--|------------|--|-------|----------------------|
| Rectifier Diode | | | | |
| Peak Repetitive Reverse Voltage | V_{RRM} | | 1600 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 25 | A |
| Surge (non-repetitive) forward current | I_{FSM} | 50 Hz Single Half Sine Wave $t_p = 10 \text{ ms}$ | 200 | A |
| Surge current capability | I^2t | $T_j = 150^\circ\text{C}$ | 200 | A^2s |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 44 | W |
| Maximum Junction Temperature | T_{jmax} | | 150 | $^\circ\text{C}$ |



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------------------------------|------------|-----------------------------|----------|------------------|
| Inverter Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 1200 | V |
| Collector current | I_C | $T_j = T_{jmax}$ | 15 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 30 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ | 60 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Inverter Diode

| | | | | |
|-------------------------------------|------------|------------------|------|------------------|
| Peak repetitive reverse voltage | V_{RRM} | | 1200 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ | 15 | A |
| Repetitive peak forward current | I_{FRM} | | 30 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ | 45 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Module Properties

Thermal Properties

| | | | | |
|---|-----------|--|---------------------------|------------------|
| Storage temperature | T_{stg} | | -40...+125 | $^\circ\text{C}$ |
| Operation temperature under switching condition | T_{op} | | -40...($T_{jmax} - 25$) | $^\circ\text{C}$ |

Isolation Properties

| | | | | | |
|----------------------------|------------|------------------|----------------------|-----------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* | $t_p = 2\text{ s}$ | 6000 | V |
| | | AC Voltage | $t_p = 1\text{ min}$ | 2500 | V |
| Creepage distance | | | | min. 12,7 | mm |
| Clearance | | | | 9,29 | mm |
| Comparative Tracking Index | CTI | | | > 200 | |

*100 % tested in production



10-FZ12PNA015M7-P840C28

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Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit | |
|-----------|--------|--------------|--------------|--------------|--------------|-----------|-----------|------------|-----|-----|------|--|
| | | V_{GE} [V] | V_{GS} [V] | V_{CE} [V] | V_{DS} [V] | I_c [A] | I_D [A] | T_j [°C] | Min | Typ | Max | |

Rectifier Diode

Static

| | | | | | | | | | |
|-------------------------|-------|--|------|----|-----------|--|--------------|------------|---------|
| Forward voltage | V_F | | | 25 | 25 125 | | 1,22 1,21 | 1,8 | V |
| Reverse leakage current | I_r | | 1600 | | 25 145 | | | 50 1100 | μA |

Thermal

| | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | 1,59 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|------|--|-----|

Inverter Switch

Static

| | | | | | | | | | |
|--------------------------------------|--------------|-------------------|----|--------|------------------|-----|----------------------|------|----------|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ | | 0,0015 | 25 | 5,4 | 6 | 6,6 | V |
| Collector-emitter saturation voltage | V_{CEsat} | | 15 | 15 | 25 125 150 | | 1,70 1,95 2,01 | 2,15 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 1200 | 25 | | | 60 | μA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | 25 | | | 500 | nA |
| Internal gate resistance | r_g | | | | | | none | | Ω |
| Input capacitance | C_{ies} | | | | | | 2900 | | pF |
| Output capacitance | C_{oes} | | 0 | 10 | 25 | | 120 | | |
| Reverse transfer capacitance | C_{res} | | | | | | 34 | | |
| Gate charge | Q_g | | 15 | 600 | 15 | 25 | 110 | | nC |

Thermal

| | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | 1,60 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|---|----------|-----|----|-----------|--|----------------|--|----|
| Turn-on delay time | $t_{d(on)}$ | $R_{goff} = 32 \Omega$ $R_{gon} = 32 \Omega$ | ± 15 | 600 | 15 | 25 150 | | 176 174 | | ns |
| Rise time | t_r | | | | | 25 150 | | 43 48 | | |
| Turn-off delay time | $t_{d(off)}$ | | | | | 25 150 | | 191 218 | | |
| Fall time | t_f | | | | | 25 150 | | 119 127 | | |
| Turn-on energy (per pulse) | E_{on} | | | | | 25 150 | | 1,548 2,008 | | |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 150 | | 0,925 1,322 | | |



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_1 [°C] | Min | Typ | Max | | |

Inverter Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|------|----|-----------|--|--------------|-----|----|
| Forward voltage | V_F | | | | 15 | 25 125 | | 1,63 1,74 | 2,1 | V |
| Reverse leakage current | I_R | | | 1200 | | 25 | | | 30 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 2,11 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|----------|-----|----|-----------|--|----------------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 293 \text{ A/}\mu\text{s}$ $di/dt = 244 \text{ A/}\mu\text{s}$ | ± 15 | 600 | 15 | 25 150 | | 11 12 | | A |
| Reverse recovery time | t_{rr} | | | | | 25 150 | | 265 423 | | ns |
| Recovered charge | Q_r | | | | | 25 150 | | 1,549 2,592 | | µC |
| Reverse recovered energy | E_{rec} | | | | | 25 150 | | 0,488 0,938 | | mWs |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 25 150 | | 92 52 | | A/µs |

Thermistor

| | | | | | | | | | | |
|----------------------------|----------------|-------------------------|--|--|--|-----|----|------|---|------|
| Rated resistance | R | | | | | 25 | | 22 | | kΩ |
| Deviation of R_{100} | $\Delta R/R$ | $R_{100} = 1484 \Omega$ | | | | 100 | -5 | | 5 | % |
| Power dissipation | P | | | | | 25 | | 5 | | mW |
| Power dissipation constant | | | | | | 25 | | 1,5 | | mW/K |
| B-value | $B_{(25/50)}$ | Tol. ±1 % | | | | 25 | | 3962 | | K |
| B-value | $B_{(25/100)}$ | Tol. ±1 % | | | | 25 | | 4000 | | K |
| Vincotech NTC Reference | | | | | | | | | I | |



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Rectifier Diode Characteristics

figure 1.
Typical forward characteristics

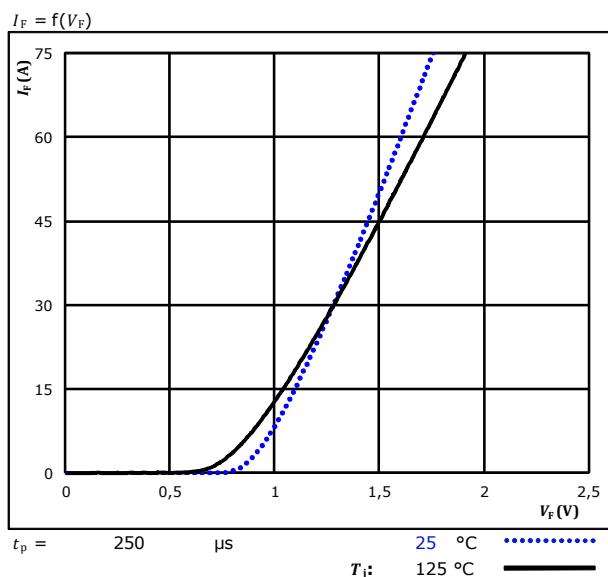
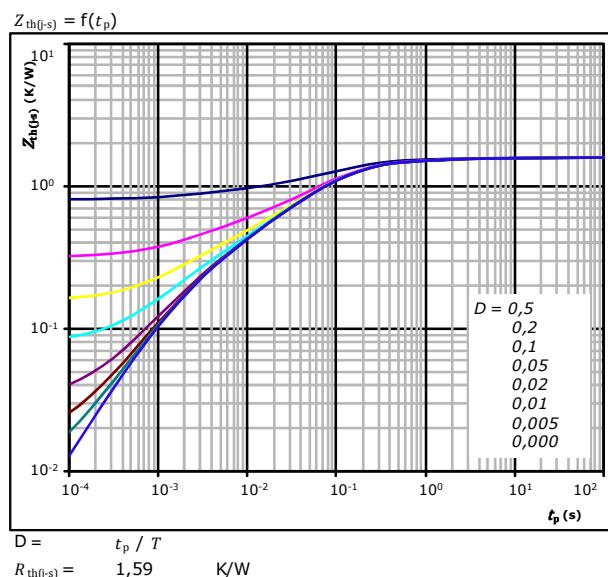


figure 2.
Transient thermal impedance as a function of pulse width



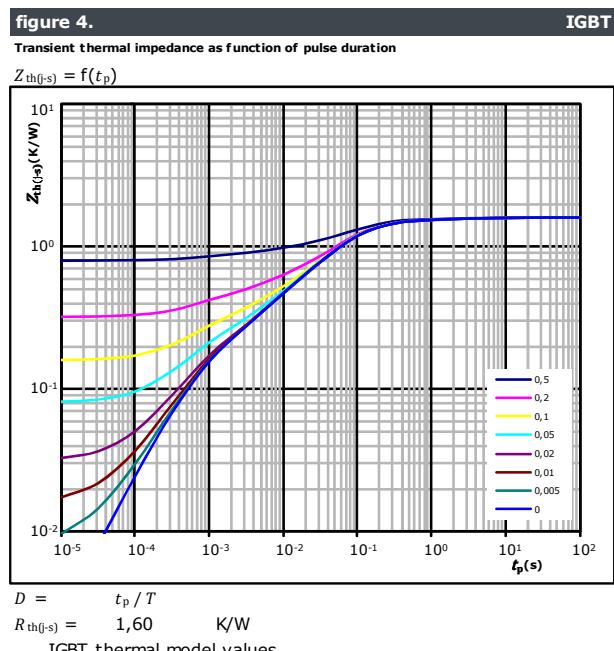
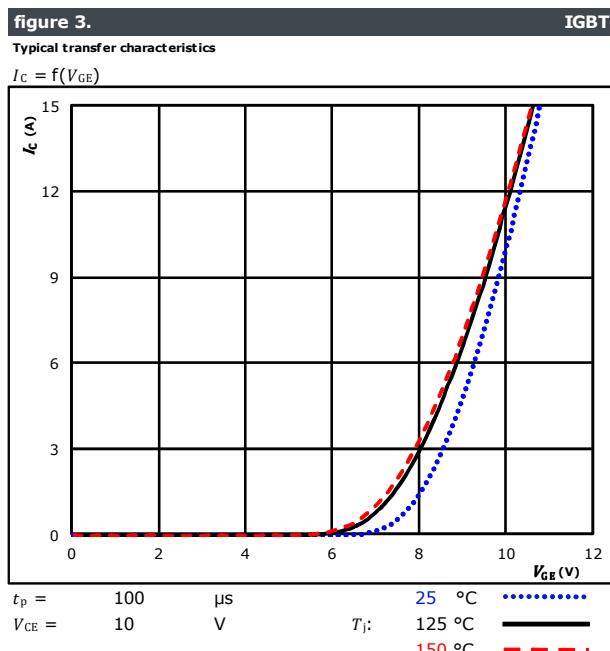
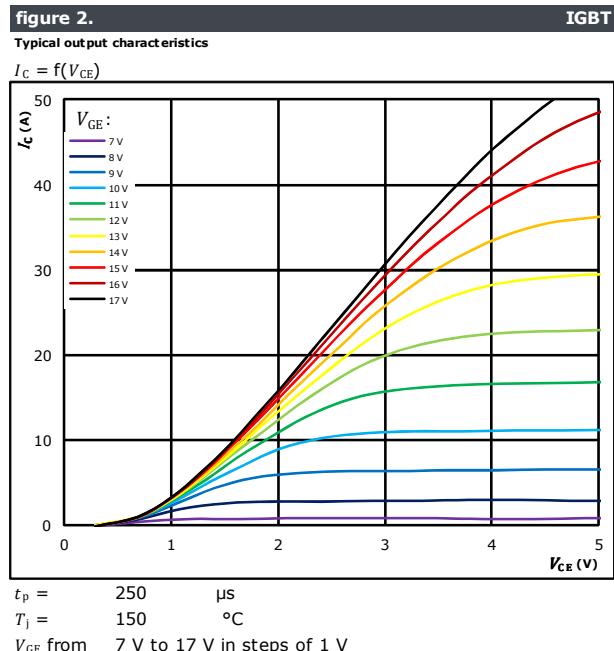
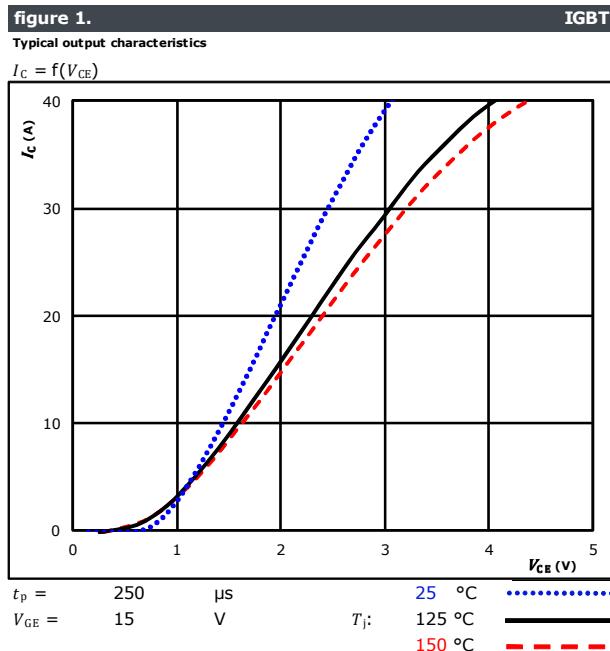
Diode thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 3,44E-02 | 9,66E+00 |
| 1,12E-01 | 1,22E+00 |
| 5,81E-01 | 1,45E-01 |
| 4,89E-01 | 5,05E-02 |
| 2,38E-01 | 9,26E-03 |
| 1,22E-01 | 1,79E-03 |
| 1,22E-01 | 1,79E-03 |



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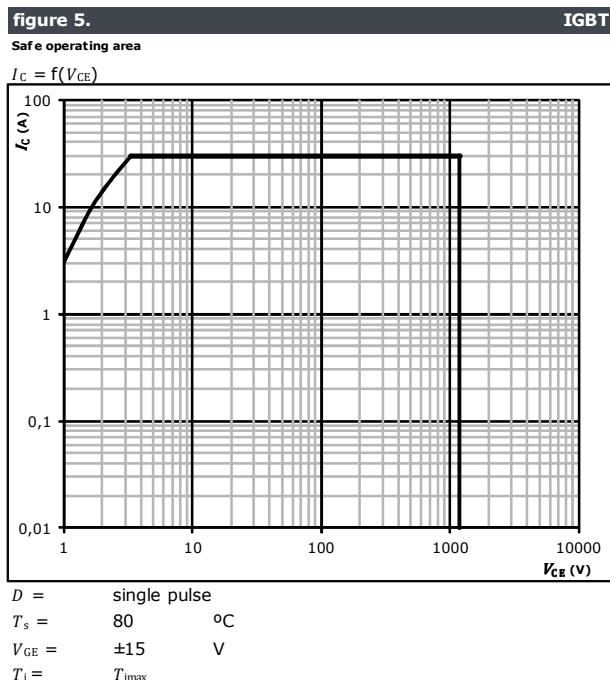
Inverter Switch Characteristics





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Inverter Switch Characteristics



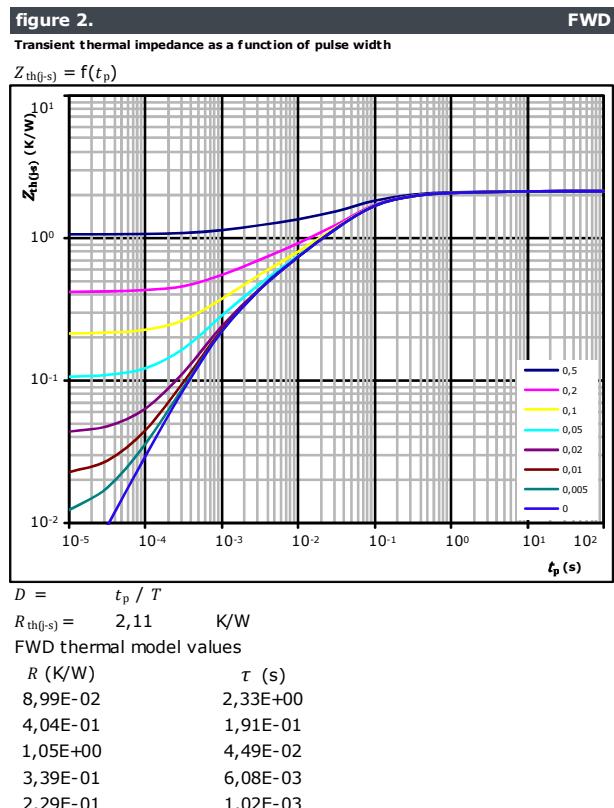
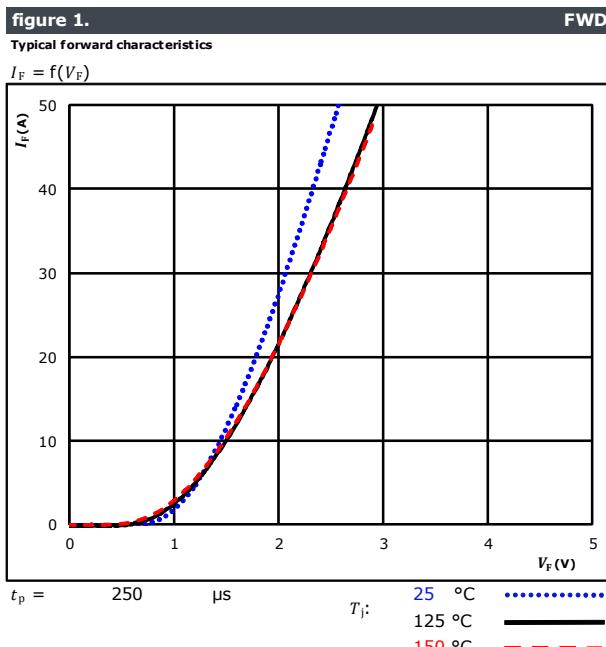


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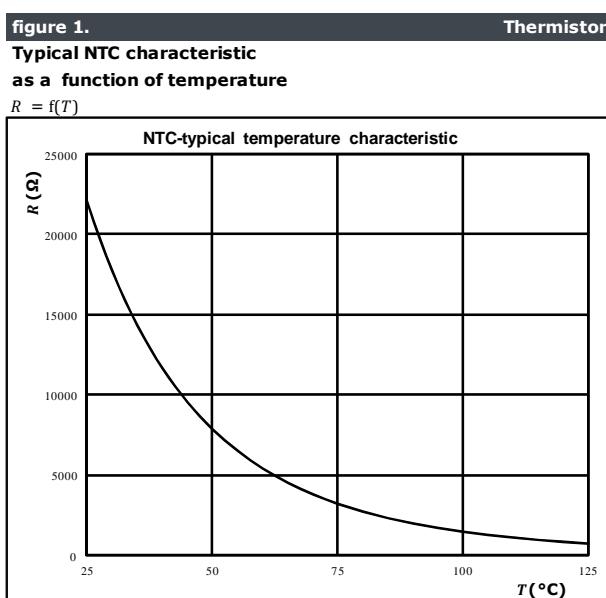
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Inverter Diode Characteristics



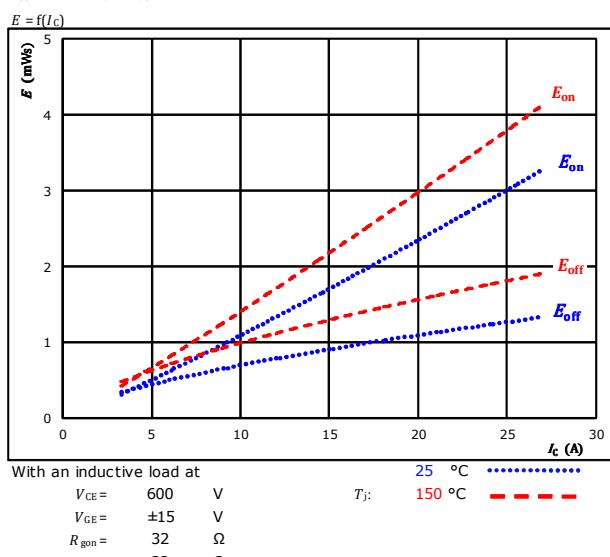
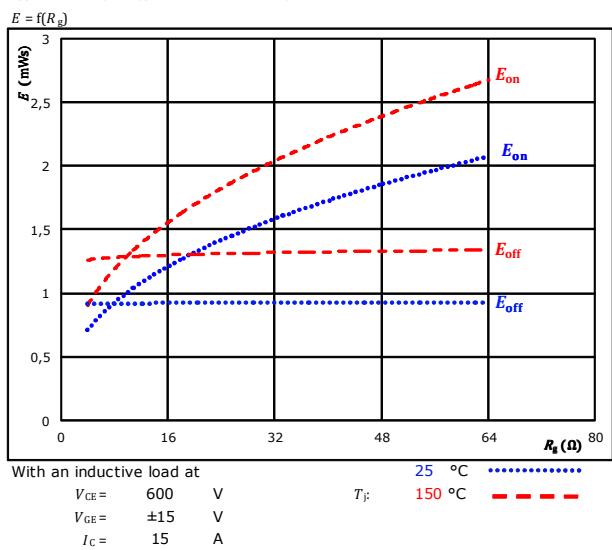
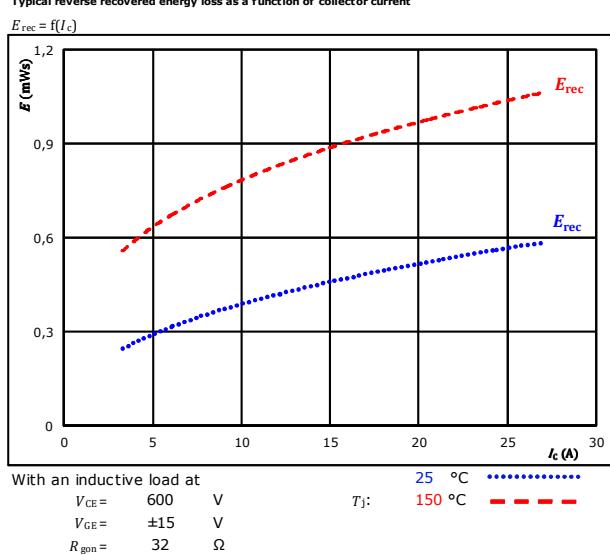
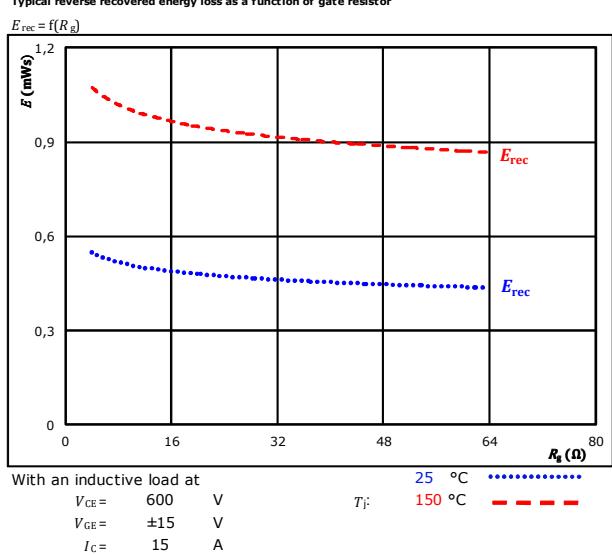
Thermistor Characteristics





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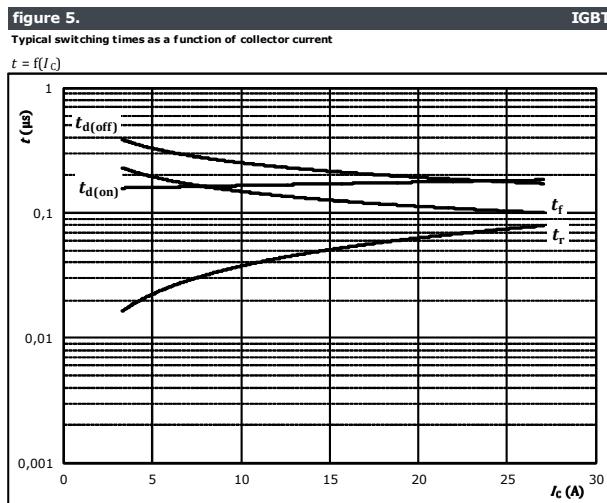
Inverter Switching Characteristics

figure 1.
Typical switching energy losses as a function of collector current**figure 2.**
Typical switching energy losses as a function of gate resistor**figure 3.**
Typical reverse recovered energy loss as a function of collector current**figure 4.**
Typical reverse recovered energy loss as a function of gate resistor



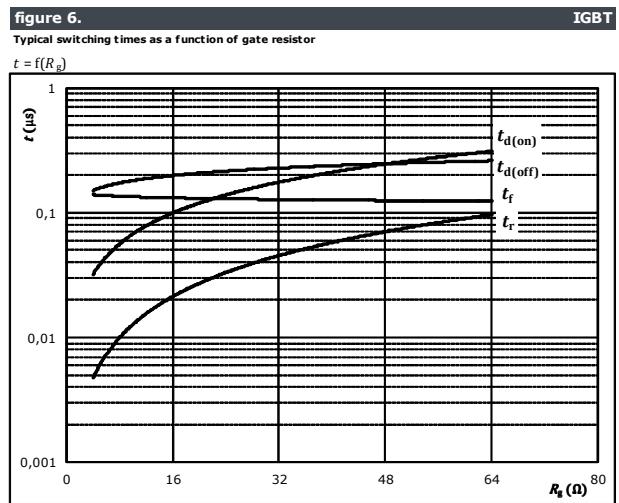
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Inverter Switching Characteristics



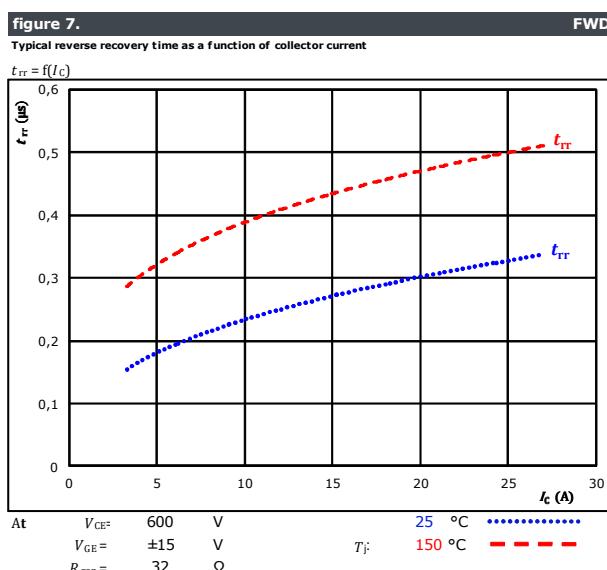
With an inductive load at

| | | |
|--------------|-----|----|
| $T_J =$ | 150 | °C |
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $R_{gon} =$ | 32 | Ω |
| $R_{goff} =$ | 32 | Ω |

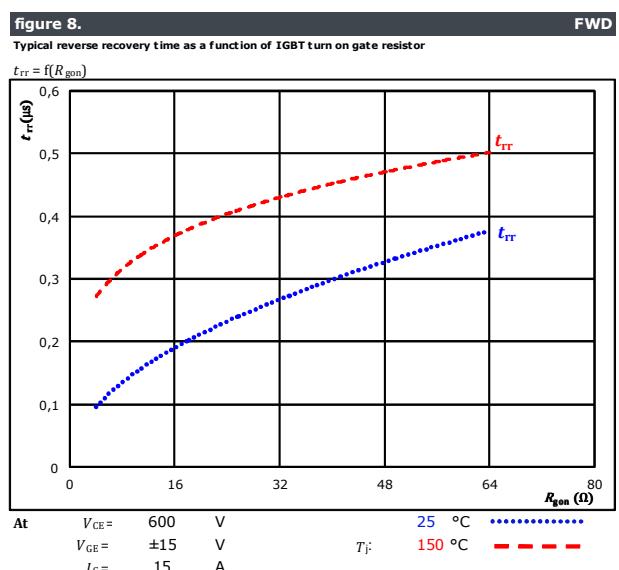


With an inductive load at

| | | |
|------------|-----|----|
| $T_J =$ | 150 | °C |
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $I_C =$ | 15 | A |



At $V_{CE} = 600$ V 25 °C $\cdots \cdots \cdots$
 $V_{GE} = \pm 15$ V $T_J = 150$ °C $- - - - -$
 $R_{gon} = 32$ Ω

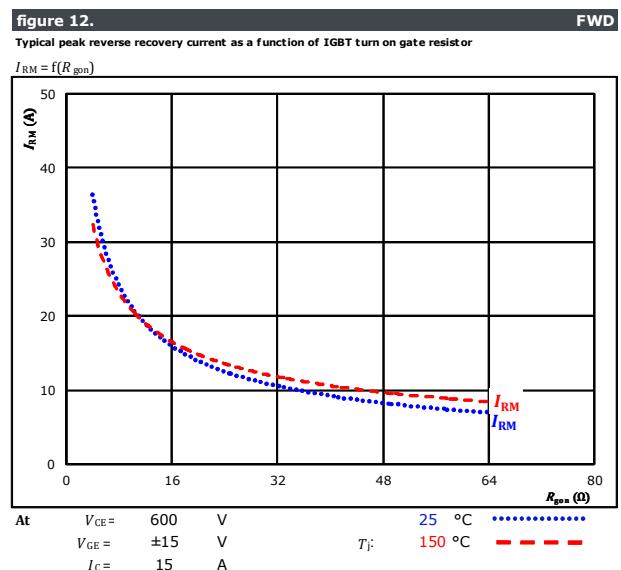
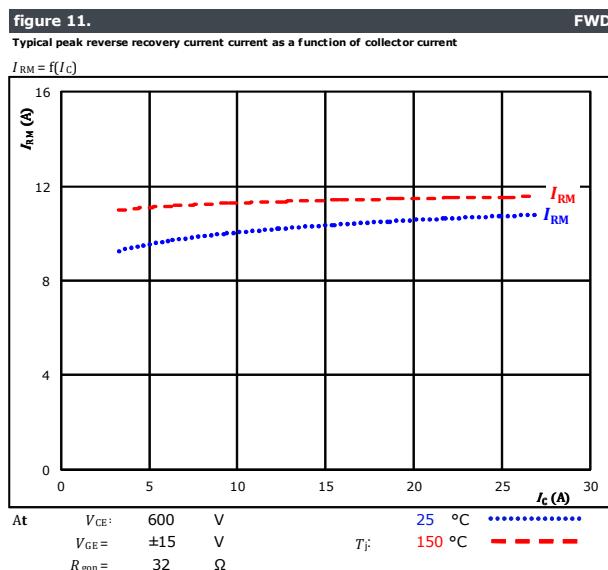
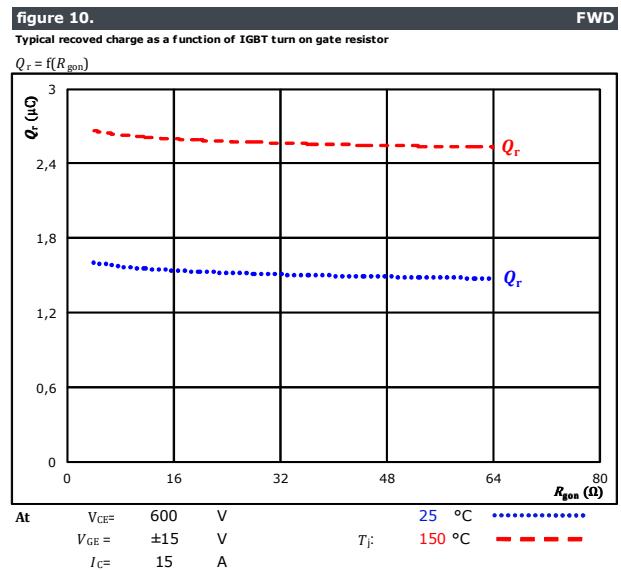
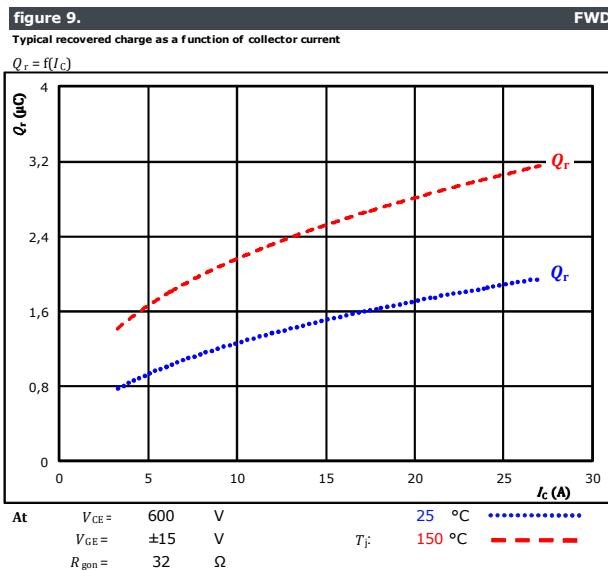


At $V_{CE} = 600$ V 25 °C $\cdots \cdots \cdots$
 $V_{GE} = \pm 15$ V $T_J = 150$ °C $- - - - -$
 $I_C = 15$ A



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Inverter Switching Characteristics

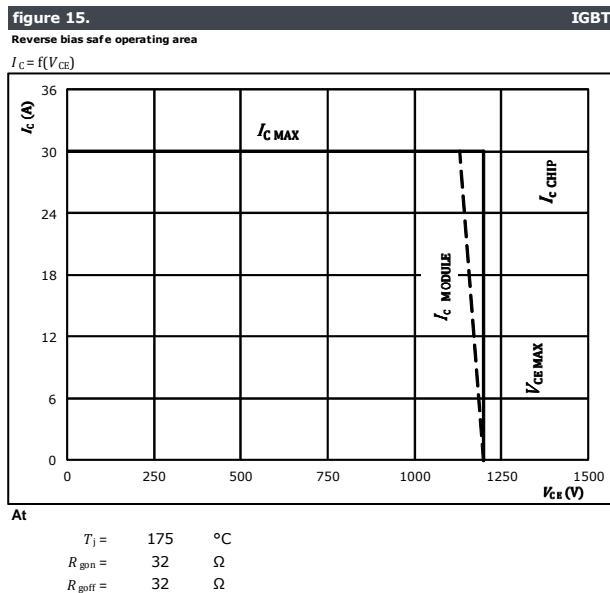
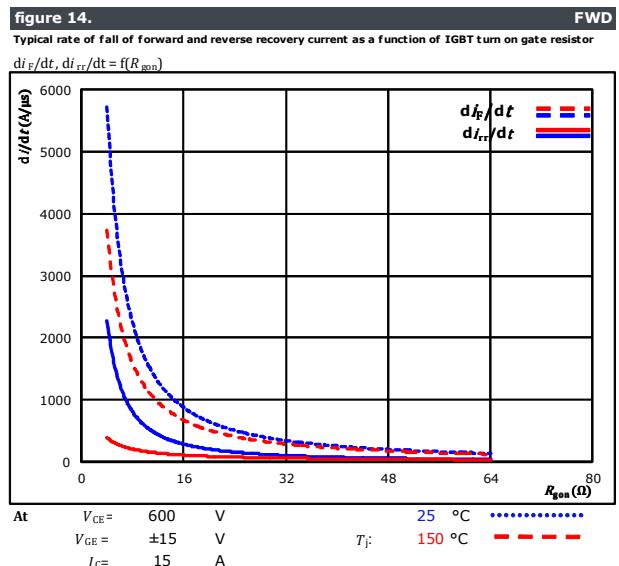
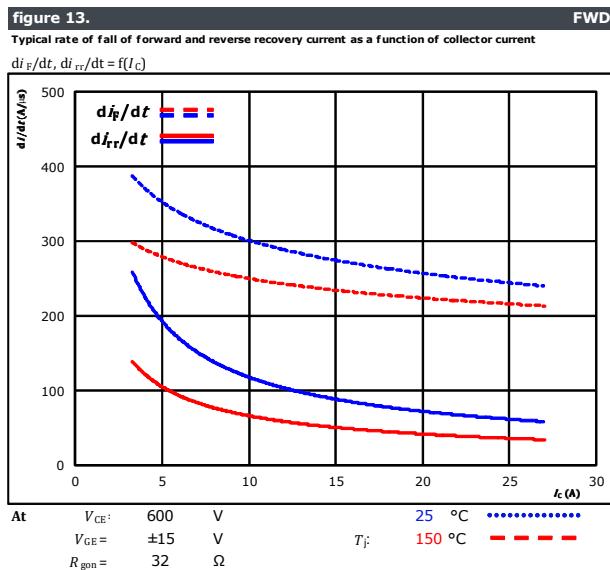




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Inverter Switching Characteristics





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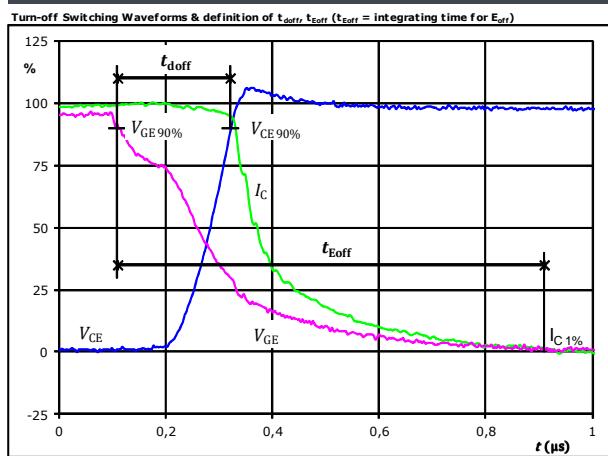
Inverter Switching Definitions

General conditions

| | | |
|------------|---|--------|
| T_j | = | 150 °C |
| R_{gon} | = | 32 Ω |
| R_{goff} | = | 32 Ω |

figure 1.

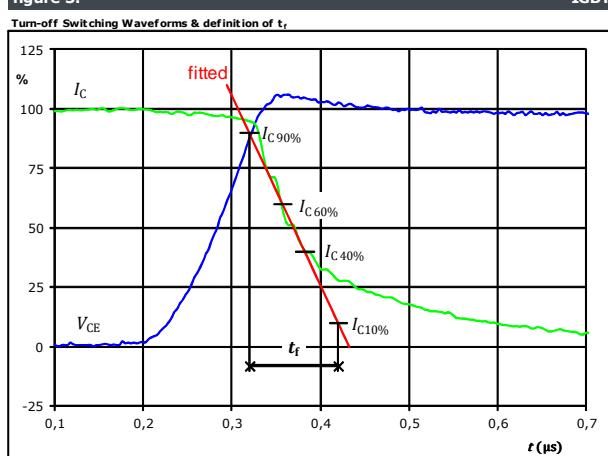
IGBT



$V_{GE\ (0\%)} = -15$ V
 $V_{GE\ (100\%)} = 15$ V
 $V_C\ (100\%) = 600$ V
 $I_C\ (100\%) = 15$ A
 $t_{doff} = 0,218$ μs
 $t_{Eoff} = 0,800$ μs

figure 3.

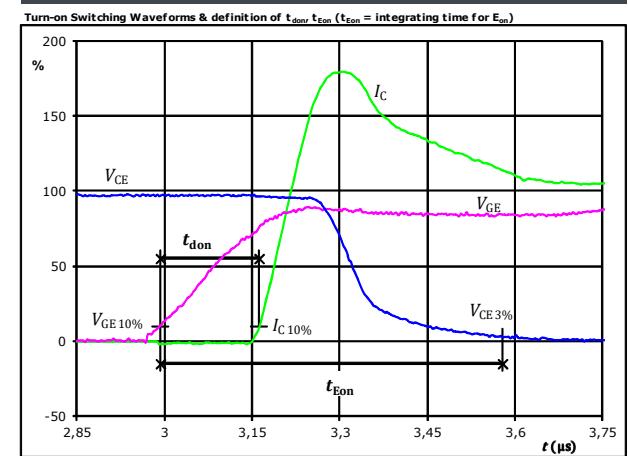
IGBT



$V_C\ (100\%) = 600$ V
 $I_C\ (100\%) = 15$ A
 $t_f = 0,127$ μs

figure 2.

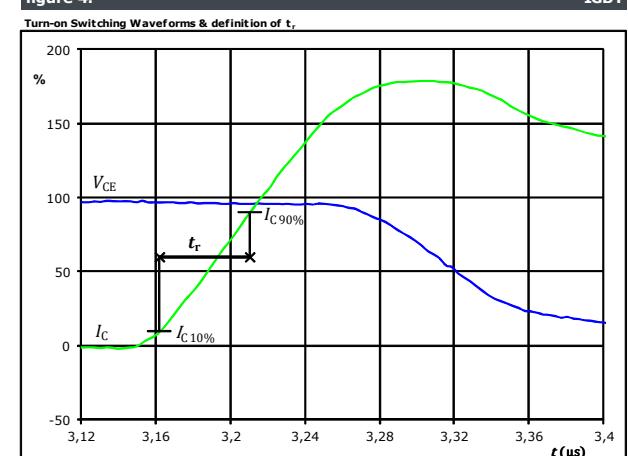
IGBT



$V_{GE\ (0\%)} = -15$ V
 $V_{GE\ (100\%)} = 15$ V
 $V_C\ (100\%) = 600$ V
 $I_C\ (100\%) = 15$ A
 $t_{don} = 0,174$ μs
 $t_{Eon} = 0,586$ μs

figure 4.

IGBT

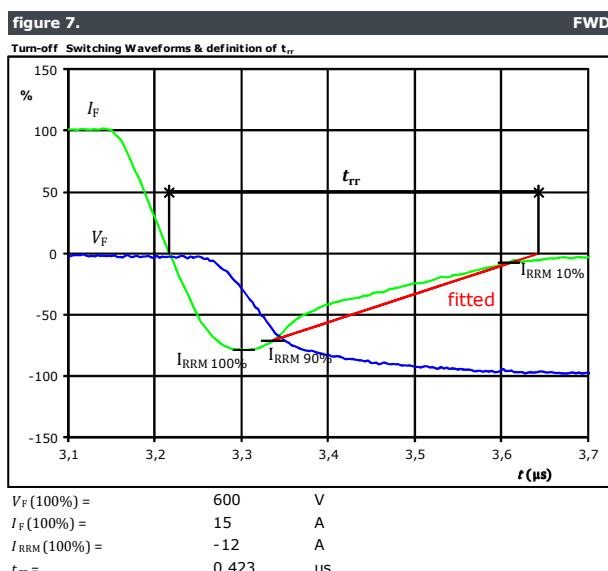
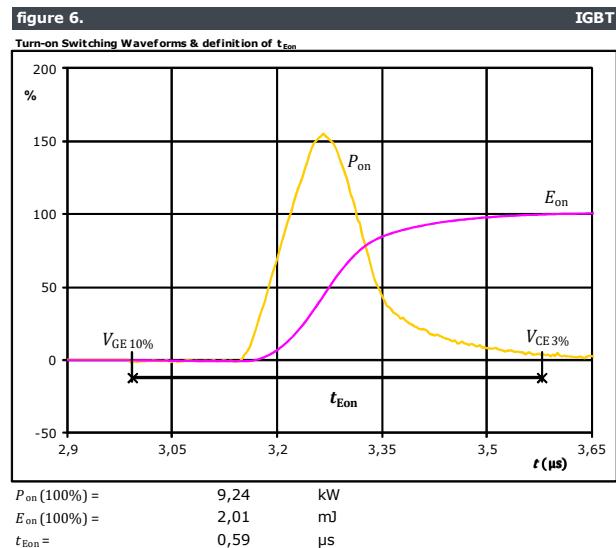
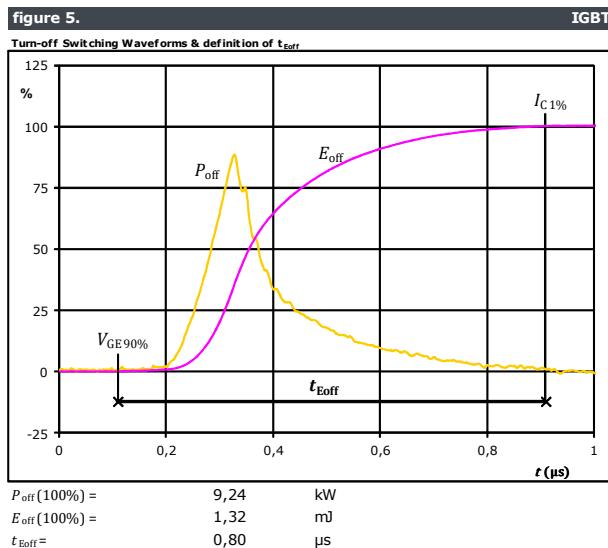


$V_C\ (100\%) = 600$ V
 $I_C\ (100\%) = 15$ A
 $t_r = 0,048$ μs



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Inverter Switching Characteristics





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Inverter Switching Characteristics

figure 8.

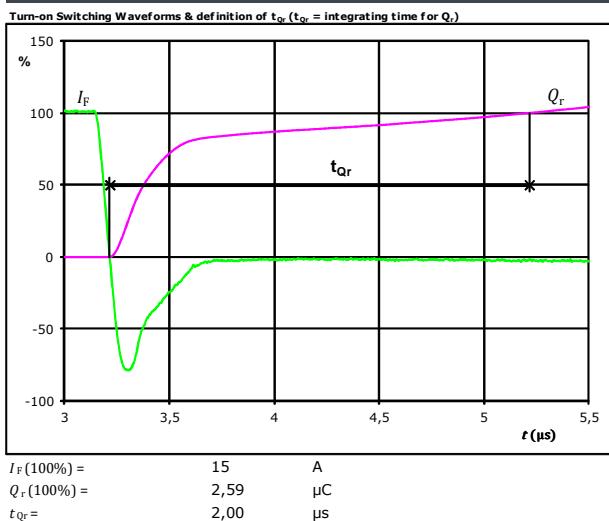
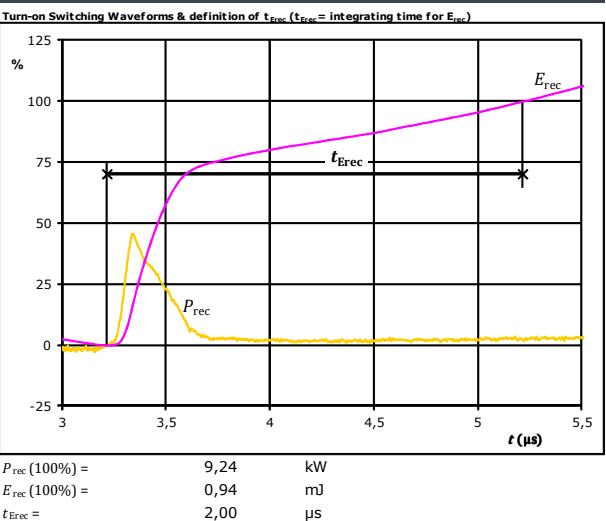


figure 9.



**10-FZ12PNA015M7-P840C28**

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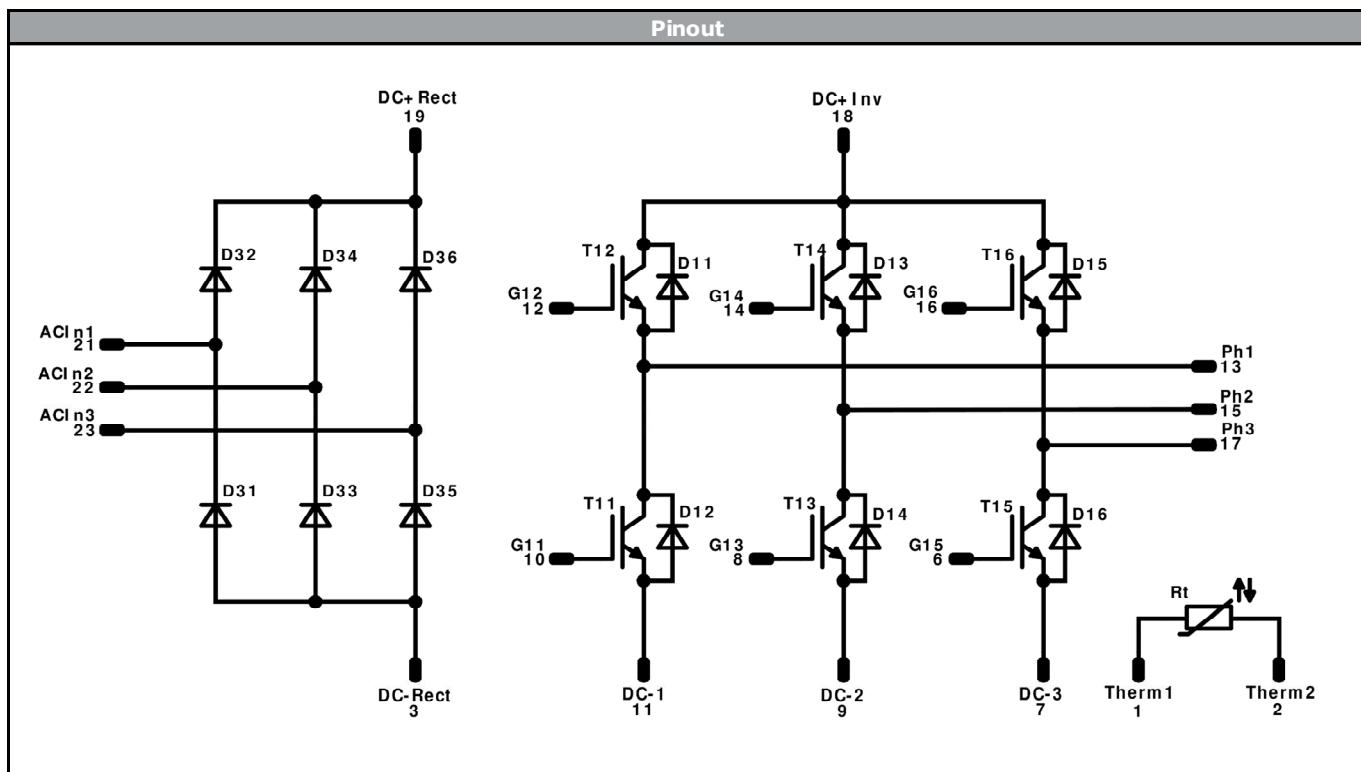
| Ordering Code & Marking | | | | | | | |
|---|---------------|------------|----------|-----------------------------|-----------|-----------|------|
| Version | | | | Ordering Code | | | |
| without thermal paste 12 mm housing with solder pins | | | | 10-FZ12PNA015M7-P840C28 | | | |
| with thermal paste 12 mm housing with solder pins | | | | 10-FZ12PNA015M7-P840C28-/3/ | | | |
| | | | | | | | |
| NN-NNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS | | | Text | Name | Date code | UL & VIN | Lot |
| | | | | NN-NNNNNNNNNNNN-TTTTTVV | WWYY | UL VIN | LLLL |
| | | Datamatrix | Type&Ver | Lot number | Serial | Date code | SSSS |
| | | | TTTTTTVV | LLLLL | SSSS | WWYY | |
| Outline | | | | | | | |
| Pin table | | | | | | | |
| Pin | X | Y | Function | | | | |
| 1 | 25,5 | 2,7 | Therm1 | | | | |
| 2 | 25,5 | 0 | Therm2 | | | | |
| 3 | 22,8 | 0 | DC-Rect | | | | |
| 4 | Not assembled | | | | | | |
| 5 | Not assembled | | | | | | |
| 6 | 13,5 | 0 | G15 | | | | |
| 7 | 10,8 | 0 | DC-3 | | | | |
| 8 | 8,1 | 0 | G13 | | | | |
| 9 | 5,4 | 0 | DC-2 | | | | |
| 10 | 2,7 | 0 | G11 | | | | |
| 11 | 0 | 0 | DC-1 | | | | |
| 12 | 0 | 19,8 | G12 | | | | |
| 13 | 0 | 22,5 | Ph1 | | | | |
| 14 | 7,5 | 19,8 | G14 | | | | |
| 15 | 7,5 | 22,5 | Ph2 | | | | |
| 16 | 15 | 19,8 | G16 | | | | |
| 17 | 15 | 22,5 | Ph3 | | | | |
| 18 | 22,8 | 22,5 | DC+Inv | | | | |
| 19 | 25,5 | 22,5 | DC+Rect | | | | |
| 20 | Not assembled | | | | | | |
| 21 | 33,5 | 15 | ACIn1 | | | | |
| 22 | 33,5 | 7,5 | ACIn2 | | | | |
| 23 | 33,5 | 0 | ACIn3 | | | | |
| Tolerance of pinpositions: ±0.5mm at the end of pins Dimension of coordinate axis is only offset without tolerance | | | | | | | |



10-FZ12PNA015M7-P840C28

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| Identification | | | | | |
|----------------|-----------|---------|---------|-----------------|---------|
| ID | Component | Voltage | Current | Function | Comment |
| D31-D36 | Rectifier | 1600 V | 25 A | Rectifier Diode | |
| T11-T16 | IGBT | 1200 V | 15 A | Inverter Switch | |
| D11-D16 | FWD | 1200 V | 15 A | Inverter Diode | |
| Rt | NTC | | | Thermistor | |



10-FZ12PNA015M7-P840C28

datasheet

Vincotech

| Packaging instruction | | | |
|---------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 135 | >SPQ | Standard | <SPQ Sample |

| Handling instruction | | | |
|--|--|--|--|
| Handling instructions for flow 0 packages see vincotech.com website. | | | |

| Package data | | | |
|---|--|--|--|
| Package data for flow 0 packages see vincotech.com website. | | | |

| UL recognition and file number | | | |
|---|--|--|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. | | |  |

| Document No.: | Date: | Modification: | Pages |
|-------------------------------|--------------|----------------------|--------------|
| 10-FZ12PNA015M7-P840C28-D1-14 | 26 Nov. 2018 | | |

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.